

Corrigendum

Corrigendum to “Interface morphology snapshots of vertically segregated thin films of semiconducting polymer/polystyrene blends”  
[Polymer 48 (2007) 2380–2386]

Fernando A. Castro <sup>a,b,\*</sup>, Carlos F.O. Graeff <sup>c</sup>, Jakob Heier <sup>a</sup>, Roland Hany <sup>a</sup>

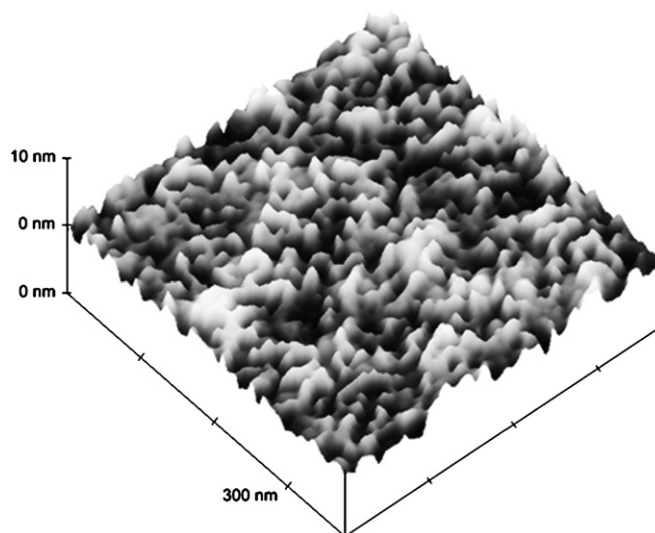
<sup>a</sup> Empa, Swiss Federal Laboratories for Materials Testing and Research, Laboratory for Functional Polymers, Überlandstr. 129, CH-8600 Dübendorf, Switzerland

<sup>b</sup> Departamento de Física e Matemática, Faculdade de Filosofia, Ciências e Letras de Ribeirão Preto, Universidade de São Paulo, Av. Bandeirantes 3900, 14040-901 Ribeirão Preto, SP, Brazil

<sup>c</sup> Departamento de Física, Faculdade de Ciências, UNESP, Av. Luíz Edmundo Carrijo Coube 14-01, 17033-360 Bauru, Brazil

Available online 4 April 2007

The height scale of Fig. 4 is incorrect by a factor of 10, it should read as 10 nm instead of 100 nm. The caption of Fig. 4 should also be corrected correspondingly: (“visible substructures with dimensions well below 100 nm” should be replaced by “visible substructures with dimensions below 10 nm”). The correct version of Fig. 4 is shown below.



DOI of original article: [10.1016/j.polymer.2007.02.059](https://doi.org/10.1016/j.polymer.2007.02.059).

\* Corresponding author. Departamento de Física e Matemática, Faculdade de Filosofia, Ciências e Letras de Ribeirão Preto (FFCLRP), Universidade de São Paulo (USP), Av. Bandeirantes 3900, 14040-901 Ribeirão Preto, São Paulo, Brazil. Tel.: +55 16 3602 3858; fax: +55 16 3602 4887.

E-mail address: [fcastro@aluno.ffclrp.br](mailto:fcastro@aluno.ffclrp.br) (F.A. Castro).